Contents

| For | eword (| v | |
|-----------------|---|----|--|
| Introduction | | | |
| List of Symbols | | | |
| | | Xi | |
| Cha | pter I Semiconductor Physics | | |
| 1.1 | Quantum Mechanics | .1 | |
| 1.2 | Crystal Structures and their Vibrations | 4 | |
| 1.3 | | | |
| 1.4 | Transport Theory | 29 | |
| 1.5 | 35 | | |
| 1.6 | References for Chapter I | 39 | |
| Chap | ter II The Relevant Equations for Plasma Instabilities | | |
| 2.1 | Maxwell's Equations | 41 | |
| 2.2 | Boltzmann's Equation | 45 | |
| 2.3 | Kinetic Energy Approach | 50 | |
| 2.4 | Other Relevant Relations | 53 | |
| 2.5 | Power Flow | 54 | |
| 2.6 | References for Chapter II | 56 | |
| Chap | ter III Methods for the Analysis of Instabilities | | |
| 3.1 | Small-Signal Analysis | 58 | |
| 3.2 | Nyquist's Instability Criterion | 67 | |
| 3.3 | Large-Signal Analysis | 71 | |
| 3.4 | References for Chapter III | 75 | |
| Chap | ter IV Instabilities of Semiconductor Plasmas | | |
| 4.1 | Gunn Oscillators and other Transferred Electron Effects | 78 | |
| | 4.1.1 Basic Principle | 78 | |
| | 4.1.2 The Domain | 81 | |
| | 4.1.3 Modes of Operation | 88 | |
| | 4.1.4 Space Charge Wave Amplifier | 93 | |
| | 4.1.5 The Isa Oscillator | 96 | |
| | 4.1.6 Further Phenomena | 98 | |

| 4.2 | The Avalanche Effect | | 99 |
|---------------|---|---|-----|
| | 4.2.1 | The Read Diode | 100 |
| | 4.2.2 | The Misawa Instability | 103 |
| | 4.2.3 | Further Avalanche-Instability Studies | 109 |
| | 4.2.4 | General Experimental Results | 111 |
| 4.3 | The Electroacoustic Effect | | |
| | 4.3.1 | Electroacoustic Gain | 115 |
| | 4.3.2 | Electroacoustic Oscillations | 119 |
| | 4.3.3 | Further Electroacoustic Instabilities | 122 |
| 4.4 | Two-Stream Interactions and Other Effects | | |
| | 4.4.1 | Two-Stream Instabilities | 123 |
| | 4.4.2 | | |
| | 56 - 1945, 1745, 18 | Fields Present | 125 |
| | 4.4.3 | Alfvén and Helicon Wave Instabilities | 129 |
| | 4.4.4 | Other Instability Effects | 136 |
| Chap | ter V | Devices | |
| 5.1 | The T | ransferred-Electron Effect | 142 |
| | 5.1.1 | Oscillators and Amplifiers | 142 |
| | 5.1.2 | Pulse Generation and Processing | 149 |
| | 5.1.3 | Gunn-Effect Technology | 164 |
| 5.2 | Avala | nche Devices | 166 |
| 5.3 | Appli | cations of Electroacoustic and Other Effects | 168 |
| Chap | ter VI | References for Chapters IV and V and Author Index | 173 |
| Subject Index | | | 200 |